

1. General description

NPN/NPN general-purpose transistor in a leadless ultra small DFN1010B-6 (SOT1216) Surface-Mounted Device (SMD) plastic package.

PNP/PNP complement: BC857QAS.

NPN/PNP complement: BC847QAPN.

2. Features and benefits

- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified
- Low package height of 0.37 mm

3. Applications

- General-purpose switching and amplification
 - Mobile applications

4. Quick reference data

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Table 1. Quid	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
V _{CEO}	collector-emitter voltage	open base		-	-	45	V
I _C	collector current			-	-	100	mA
Per transistor							
h _{FE}	DC current gain	V_{CE} = 5 V; I _C = 2 mA; T _{amb} = 25 °C		200	-	450	





45 V, 100 mA NPN/NPN general-purpose transistor

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1		6 5 4
2	B1	base TR1		
3	C2	collector TR2	2 5	$\begin{pmatrix} TR1 \\ TR1 \end{pmatrix}$
4	E2	emitter TR2		
5	B2	base TR2		_
6	C1	collector TR1	Transparent top view	sym020
7	C1	collector TR1	DFN1010B-6 (SOT1216)	
8	C2	collector TR2		

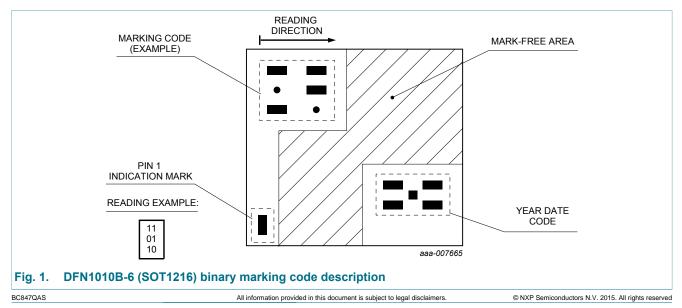
6. Ordering information

Table 3. Ordering in	formation		
Type number	Package		
	Name	Description	Version
BC847QAS	DFN1010B-6	DFN1010B-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1216

7. Marking

Table 4.Marking codes

Type number	Marking code
BC847QAS	00 01 00



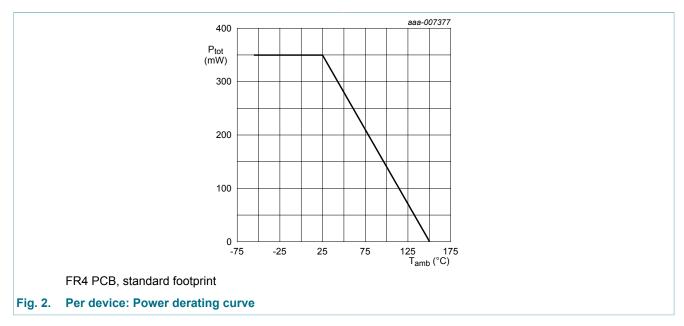
8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transis	tor					
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	45	V
V _{EBO}	emitter-base voltage	open collector		-	6	V
I _C	collector current			-	100	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	200	mA
I _{BM}	peak base current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	230	mW
Per device		I	1	1		
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	350	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

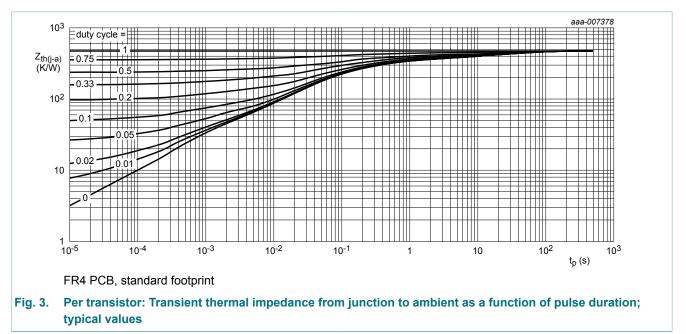
[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



9. Thermal characteristics

Table 6. The	rmal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit	
Per transistor	Per transistor							
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	543	K/W	
Per device								
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	357	K/W	

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



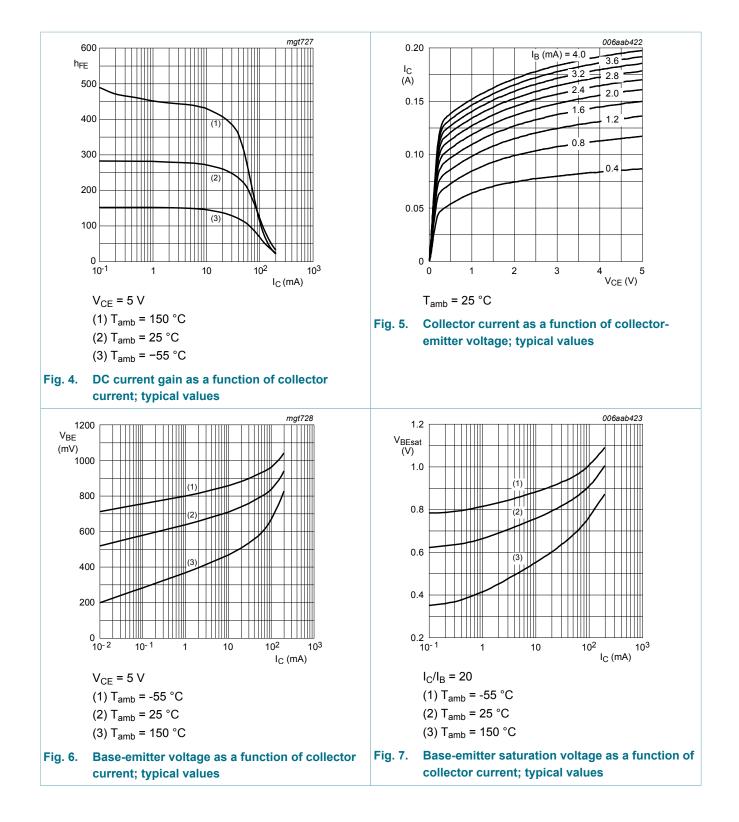
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transis	tor					
I _{CBO}	collector-base cut-off	V_{CB} = 30 V; I _E = 0 A; T _j = 150 °C	-	-	5	μA
	current	V _{CB} = 30 V; I _E = 0 A; T _{amb} = 25 °C	-	-	15	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	100	nA
h _{FE}	DC current gain	V_{CE} = 5 V; I _C = 2 mA; T _{amb} = 25 °C	200	-	450	
V _{CEsat}	collector-emitter	I_{C} = 10 mA; I_{B} = 0.5 mA; T_{amb} = 25 °C	-	-	100	mV
	saturation voltage	I_{C} = 100 mA; I_{B} = 5 mA; pulsed; t_{p} ≤ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	300	mV
V _{BEsat}	base-emitter saturation	I_{C} = 10 mA; I_{B} = 0.5 mA; T_{amb} = 25 °C	-	760	-	mV
	voltage	I_{C} = 100 mA; I_{B} = 5 mA; pulsed; $t_{p} \le 300$ μs; δ ≤ 0.02; T_{amb} = 25 °C	-	900	-	mV
V _{BE}	base-emitter voltage	V_{CE} = 5 V; I _C = 2 mA; T _{amb} = 25 °C	600	660	725	mV
		V_{CE} = 5 V; I _C = 10 mA; T _{amb} = 25 °C	-	710	820	mV
C _C	collector capacitance	V _{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	-	4	pF
C _E	emitter capacitance	V _{EB} = 0.5 V; I _C = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	11	-	pF
f _T	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}; f = 100 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$	100	-	-	MHz
NF	noise figure	V _{CE} = 5 V; I _C = 0.2 mA; R _S = 2 kΩ; f = 1 MHz; B = 200 Hz; T _{amb} = 25 °C	-	-	10	dB

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BC847QAS

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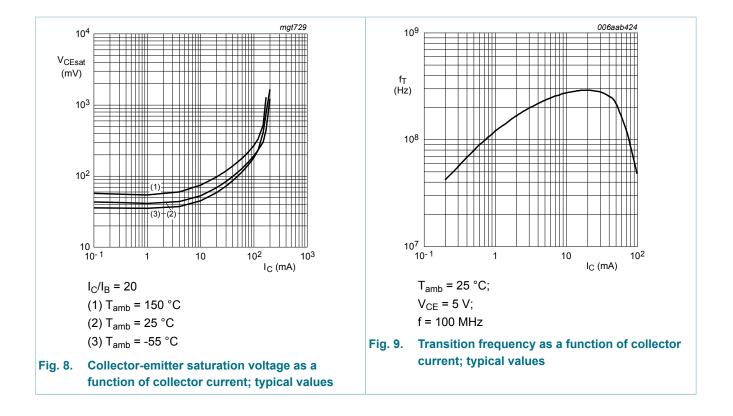
BC847QAS

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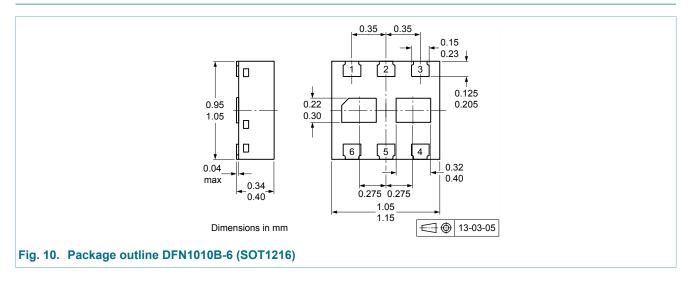


11. Test information

11.1 Quality information

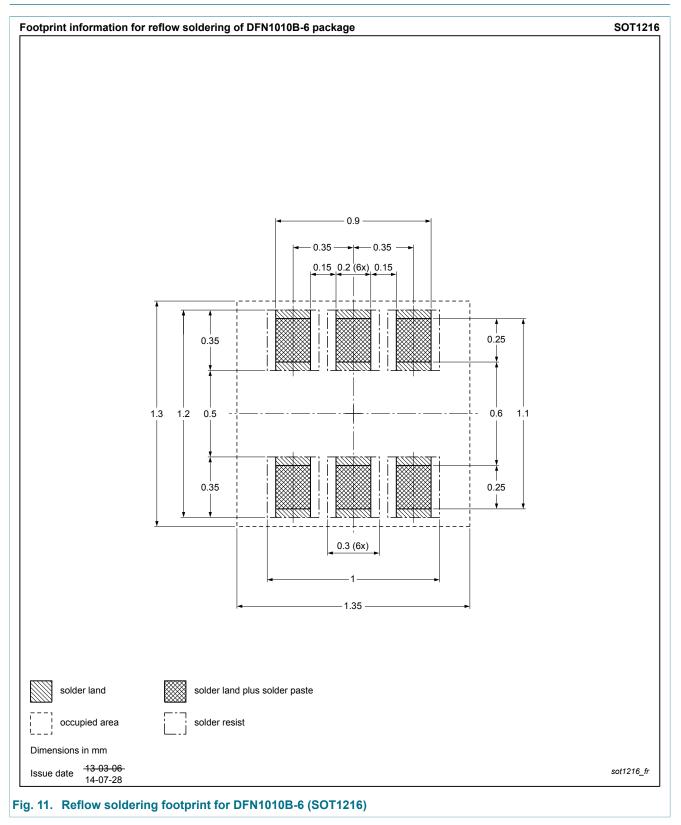
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



BC847QAS

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14. Revision history

Table 8. Revision hi	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC847QAS v.2	20150708	Product data sheet	-	BC847QAS v.1
Modification:	Change of binary m	arking code position.		
BC847QAS v.1	20140729	Product data sheet	-	-

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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